

## LM3303/LM3403 Quad Operational Amplifiers

### General Description

The LM3303 and LM3403 are monolithic quad operational amplifiers consisting of four independent high gain, internally frequency compensated, operational amplifiers designed to operate from a single power supply or dual power supplies over a wide range of voltages. The common mode input range includes the negative supply, thereby eliminating the necessity for external biasing components in many applications.

### Features

- Input common mode voltage range includes ground or negative supply
- Output voltage can swing to ground or negative supply

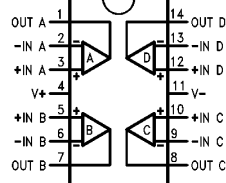
- Four internally compensated operational amplifiers in a single package
- Wide power supply range single supply of 3.0V to 36V dual supply of  $\pm 1.5V$  to  $\pm 18V$
- Class AB output stage for minimal crossover distortion
- Short circuit protected outputs
- High open loop gain 200k
- LM741 operational amplifier type performance

### Applications

- Filters
- Voltage controlled oscillators

### Connection Diagram

14-Lead DIP and SO-14 Package



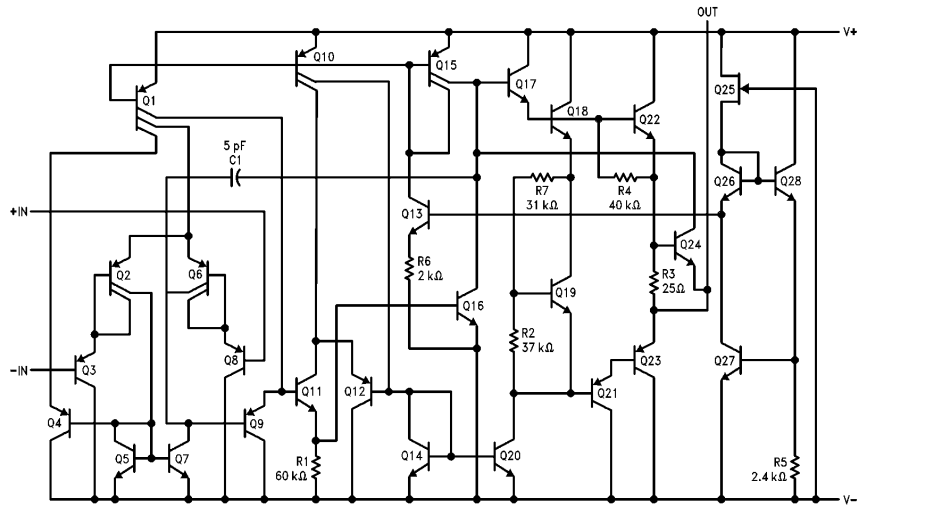
Top View

TL/H/10064-1

### Order Information

| Device Code | Package Code | Package Description  |
|-------------|--------------|----------------------|
| LM3303J     | J14A         | Ceramic DIP          |
| LM3303N     | N14A         | Molded DIP           |
| LM3303M     | M14A         | Molded Surface Mount |
| LM3403J     | J14A         | Ceramic DIP          |
| LM3403N     | N14A         | Molded DIP           |
| LM3403M     | M14A         | Molded Surface Mount |

### Equivalent Circuit ( $\frac{1}{4}$ of Circuit)



TL/H/10064-2

## Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

|                                           |                 |
|-------------------------------------------|-----------------|
| Storage Temperature Range                 |                 |
| Ceramic DIP                               | −65°C to +175°C |
| Molded DIP and SO-14                      | −65°C to +150°C |
| Operating Temperature Range               |                 |
| Industrial (LM3303)                       | −40°C to +85°C  |
| Commercial (LM3403)                       | 0°C to +70°C    |
| Lead Temperature                          |                 |
| Ceramic DIP (Soldering, 60 sec.)          | 300°C           |
| Molded DIP and SO-14 (Soldering, 10 sec.) | 265°C           |

Internal Power Dissipation (Notes 1, 2)

|                 |       |
|-----------------|-------|
| 14L-Ceramic DIP | 1.36W |
| 14L-Molded DIP  | 1.04W |
| SO-14           | 0.93W |

Supply Voltage between V+ and V−

36V

Differential Input Voltage (Note 3)

±30V

Input Voltage

(V−) − 0.3V to V+

ESD Tolerance

(To Be Determined)

## LM3303 and LM3403

**Electrical Characteristics**  $T_A = 25^\circ\text{C}$ ,  $V_{CC} = \pm 15\text{V}$ , unless otherwise specified

| Symbol   | Parameter                                             |                         | Conditions                                                        | LM3303     |              |     | LM3403     |              |     | Units            |
|----------|-------------------------------------------------------|-------------------------|-------------------------------------------------------------------|------------|--------------|-----|------------|--------------|-----|------------------|
|          |                                                       |                         |                                                                   | Min        | Typ          | Max | Min        | Typ          | Max |                  |
| $V_{IO}$ | Input Offset Voltage                                  |                         |                                                                   |            | 2.0          | 8.0 |            | 2.0          | 8.0 | mV               |
| $I_{IO}$ | Input Offset Current                                  |                         |                                                                   |            | 30           | 75  |            | 30           | 50  | nA               |
| $I_{IB}$ | Input Bias Current                                    |                         |                                                                   |            | 200          | 500 |            | 200          | 500 | nA               |
| $Z_I$    | Input Impedance                                       |                         |                                                                   | 0.3        | 1.0          |     | 0.3        | 1.0          |     | M $\Omega$       |
| $I_{CC}$ | Supply Current                                        |                         | $V_O = 0\text{V}$ , $R_L = \infty$                                |            | 2.8          | 7.0 |            | 2.8          | 7.0 | mA               |
| CMR      | Common Mode Rejection                                 |                         | $R_S \leq 10\text{ k}\Omega$                                      | 70         | 90           |     | 70         | 90           |     | dB               |
| $V_{IR}$ | Input Voltage Range                                   |                         |                                                                   | +12V to V− | +12.5V to V− |     | +13V to V− | +13.5V to V− |     | V                |
| PSRR     | Power Supply Rejection Ratio                          |                         |                                                                   |            | 30           | 150 |            | 30           | 150 | $\mu\text{V/V}$  |
| $I_{OS}$ | Output Short Circuit Current (Per Amplifier) (Note 4) |                         |                                                                   | ±10        | ±30          | ±45 | ±10        | ±30          | ±45 | mA               |
| $A_{VS}$ | Large Signal Voltage Gain                             |                         | $V_O = \pm 10\text{V}$ ,<br>$R_L \geq 2.0\text{ k}\Omega$         | 20         | 200          |     | 20         | 200          |     | V/mV             |
| $V_{OP}$ | Output Voltage Swing                                  |                         | $R_L = 10\text{ k}\Omega$                                         | ±12        | 12.5         |     | ±12        | +13.5        |     | V                |
|          |                                                       |                         | $R_L = 2.0\text{ k}\Omega$                                        | ±10        | 12           |     | ±10        | ±13          |     |                  |
| TR       | Transient Response                                    | Rise Time/<br>Fall Time | $V_O = 50\text{ mV}$ ,<br>$A_V = 1.0$ , $R_L = 10\text{ k}\Omega$ |            | 0.3          |     |            | 0.3          |     | $\mu\text{s}$    |
|          |                                                       | Overshoot               | $V_O = 50\text{ mV}$ ,<br>$A_V = 1.0$ , $R_L = 10\text{ k}\Omega$ |            | 5.0          |     |            | 5.0          |     | %                |
| BW       | Bandwidth                                             |                         | $V_O = 50\text{ mV}$ ,<br>$A_V = 1.0$ , $R_L = 10\text{ k}\Omega$ |            | 1.0          |     |            | 1.0          |     | MHz              |
| SR       | Slew Rate                                             |                         | $V_I = -10\text{V to } +10\text{V}$ ,<br>$A_V = 1.0$              |            | 0.6          |     |            | 0.6          |     | V/ $\mu\text{s}$ |

### LM3303 and LM3403 (Continued)

Electrical Characteristics  $T_A = 25^\circ\text{C}$ ,  $V_{CC} = \pm 15\text{V}$ , unless otherwise specified

The following specifications apply for  $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$  for the LM3303, and  $0^\circ\text{C} \leq T_A \leq +70^\circ\text{C}$  for the LM3403

| Symbol                   | Parameter                                    | Conditions                                                | LM3303   |     |      | LM3403   |     |     | Units                        |
|--------------------------|----------------------------------------------|-----------------------------------------------------------|----------|-----|------|----------|-----|-----|------------------------------|
|                          |                                              |                                                           | Min      | Typ | Max  | Min      | Typ | Max |                              |
| $V_{IO}$                 | Input Offset Voltage                         |                                                           |          |     | 10   |          |     | 10  | mV                           |
| $\Delta V_{IO}/\Delta T$ | Input Offset Voltage Temperature Sensitivity |                                                           |          | 10  |      |          | 10  |     | $\mu\text{V}/^\circ\text{C}$ |
| $I_{IO}$                 | Input Offset Current                         |                                                           |          |     | 250  |          |     | 200 | nA                           |
| $\Delta I_{IO}/\Delta T$ | Input Offset Current Temperature Sensitivity |                                                           |          | 50  |      |          | 50  |     | $\text{pA}/^\circ\text{C}$   |
| $I_{IB}$                 | Input Bias Current                           |                                                           |          |     | 1000 |          |     | 800 | nA                           |
| $A_{VS}$                 | Large Signal Voltage Gain                    | $V_O = \pm 10\text{V}$ ,<br>$R_L \geq 2.0\text{ k}\Omega$ | 15       |     |      | 15       |     |     | V/mV                         |
| $V_{OP}$                 | Output Voltage Swing                         | $R_L = 2.0\text{ k}\Omega$                                | $\pm 10$ |     |      | $\pm 10$ |     |     | V                            |

### LM3303 and LM3403

Electrical Characteristics  $T_A = 25^\circ\text{C}$ ,  $V_+ = 5.0\text{V}$ ,  $V_- = \text{GND}$ , unless otherwise specified

| Symbol   | Parameter                     | Conditions                                                            | LM3303     |      |     | LM3403     |      |     | Units                  |
|----------|-------------------------------|-----------------------------------------------------------------------|------------|------|-----|------------|------|-----|------------------------|
|          |                               |                                                                       | Min        | Typ  | Max | Min        | Typ  | Max |                        |
| $V_{IO}$ | Input Offset Voltage          |                                                                       |            |      | 8.0 |            | 2.0  | 8.0 | mV                     |
| $I_{IO}$ | Input Offset Current          |                                                                       |            |      | 75  |            | 30   | 50  | nA                     |
| $I_{IB}$ | Input Bias Current            |                                                                       |            |      | 500 |            | 200  | 500 | nA                     |
| $I_{CC}$ | Supply Current                |                                                                       |            | 2.5  | 7.0 |            | 2.5  | 7.0 | mA                     |
| PSRR     | Power Supply Rejection Ratio  |                                                                       |            |      | 150 |            |      | 150 | $\mu\text{V}/\text{V}$ |
| $A_{VS}$ | Large Signal Voltage Gain     | $R_L \geq 2.0\text{ k}\Omega$                                         | 20         | 200  |     | 20         | 200  |     | V/mV                   |
| $V_{OP}$ | Output Voltage Swing (Note 5) | $R_L = 10\text{ k}\Omega$                                             | 3.3        |      |     | 3.3        |      |     | V                      |
|          |                               | $5.0\text{V} \leq V_+ \leq 30\text{V}$ ,<br>$R_L = 10\text{ k}\Omega$ | (V+) – 2.0 |      |     | (V+) – 2.0 |      |     |                        |
| CS       | Channel Separation            | $1.0\text{ Hz} \leq f \leq 20\text{ kHz}$<br>(Input Referenced)       |            | –120 |     |            | –120 |     | dB                     |

**Note 1:**  $T_{J\text{ Max}} = 150^\circ\text{C}$  for the Molded DIP and SO-14, and  $175^\circ\text{C}$  for the Ceramic DIP.

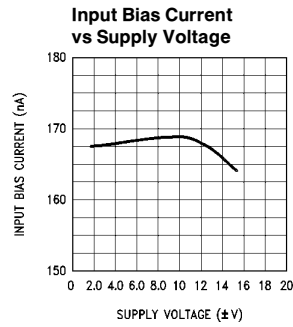
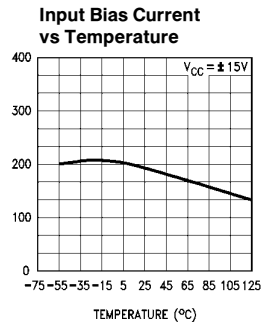
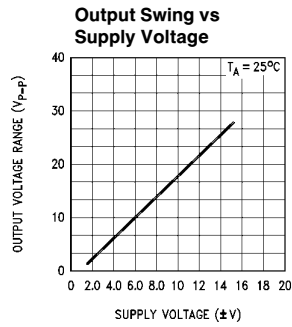
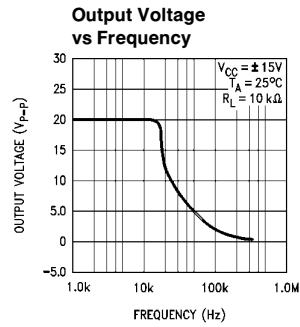
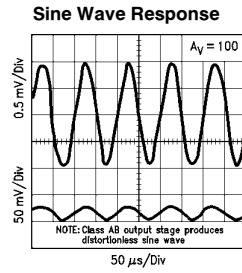
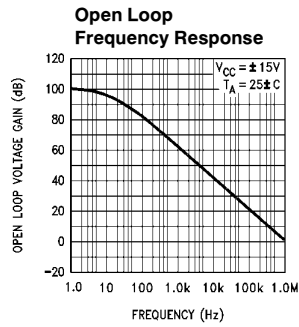
**Note 2:** Ratings apply to ambient temperature at  $25^\circ\text{C}$ . Above this temperature, derate the 14L-Ceramic DIP at  $9.1\text{ mW}/^\circ\text{C}$ , the 14L-Molded DIP at  $8.3\text{ mW}/^\circ\text{C}$ , and the SO-14 at  $7.5\text{ mW}/^\circ\text{C}$ .

**Note 3:** For supply voltage less than 30V between  $V_+$  and  $V_-$ , the absolute maximum input voltage is equal to the supply voltage.

**Note 4:** Not to exceed maximum package power dissipation.

**Note 5:** Output will swing to ground.

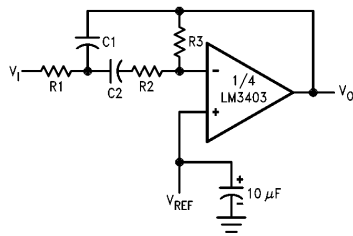
# Typical Performance Characteristics



TL/H/10064-3

## Typical Applications

### Multiple Feedback Bandpass Filter



TL/H/10064-4

$f_0$  = center frequency

BW = Bandwidth

R in k $\Omega$

C in  $\mu$ F

$$Q = \frac{f_0}{BW} < 10$$

$$C1 = C2 = \frac{Q}{3}$$

$R1 = R2 = 1 \text{ k}\Omega$   $R3 = 9Q^2 - 1$  } Using scaling factors in these expressions.

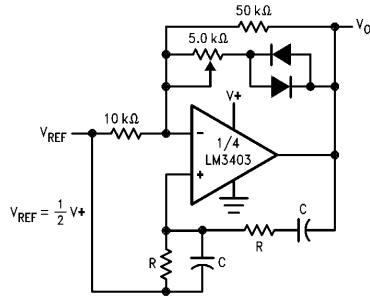
If source impedance is high or varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Design example:

given:  $Q = 5$ ,  $f_0 = 1 \text{ kHz}$   
 Let  $R1 = R2 = 10 \text{ k}\Omega$   
 then  $R3 = 9(5)^2 - 10$   
 $R3 = 215 \text{ k}\Omega$

$$C = \frac{5}{3} = 1.6 \text{ nF}$$

### Wein Bridge Oscillator



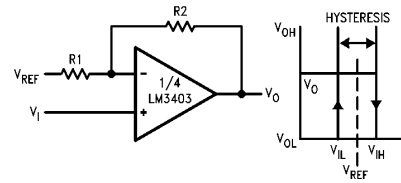
TL/H/10064-5

$$f_0 = \frac{1}{2\pi RC} \text{ for } f_0 = 1 \text{ kHz}$$

$R = 16 \text{ k}\Omega$

$C = 0.01 \text{ }\mu\text{F}$

### Comparator with Hysteresis



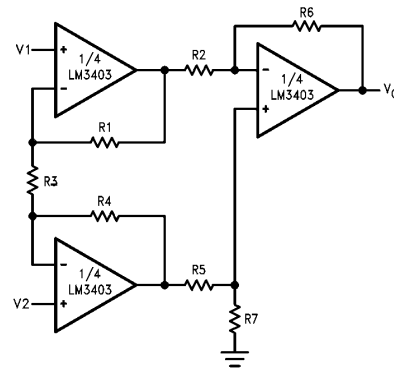
TL/H/10064-6

$$V_{IL} = \frac{R1}{R1 + R2} (V_{OL} - V_{REF}) + V_{REF}$$

$$V_{IH} = \frac{R1}{R1 + R2} (V_{OH} - V_{REF}) + V_{REF}$$

$$H = \frac{R1}{R1 + R2} (V_{OH} - V_{OL})$$

### High Impedance Differential Amplifier



TL/H/10064-7

$$V_{OUT} = C(1 + a + b)(V2 - V1)$$

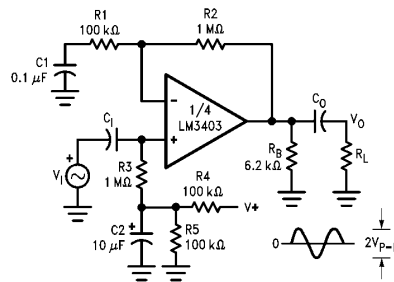
$$\frac{R2}{R5} = \frac{R6}{R7} \text{ for best CMRR}$$

$$R1 = R4$$

$$R2 = R5$$

$$\text{Gain} = \frac{R6}{R5} \left( 1 + \frac{2R1}{R3} \right) = C(1 + a + b)$$

### AC Coupled Non-Inverting Amplifier



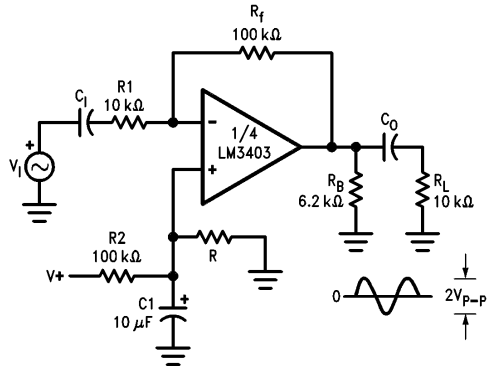
TL/H/10064-9

$$A_v = 1 + \frac{R2}{R1}$$

$$A_v = 11 \text{ (as shown)}$$

## Typical Applications (Continued)

### AC Coupled Inverting Amplifier

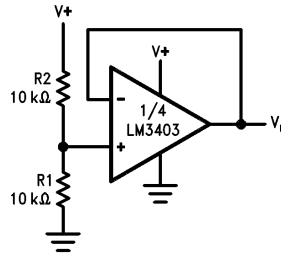


TL/H/10064-8

$$A_V = \frac{R_f}{R_1}$$

$$A_V = 10 \text{ (as shown)}$$

### Voltage Reference

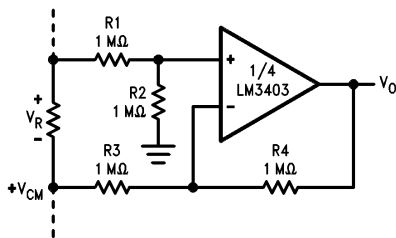


TL/H/10064-10

$$V_O = \frac{R_1}{R_1 + R_2} \left( = \frac{V_+}{2} \text{ as shown} \right)$$

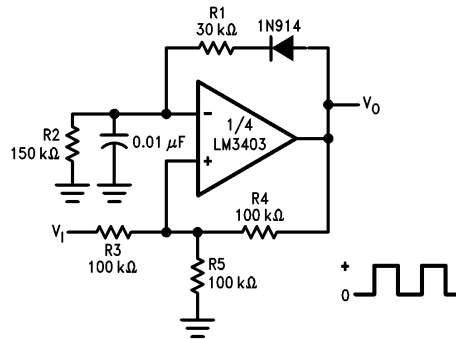
$$V_O = \frac{1}{2} V_+$$

### Ground Referencing a Differential Input Signal



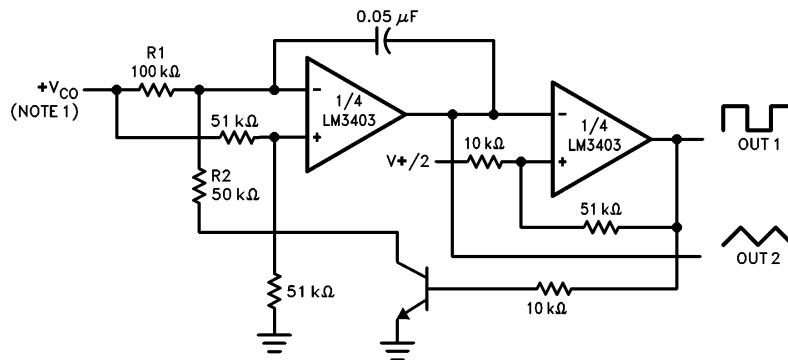
TL/H/10064-11

### Pulse Generator



TL/H/10064-14

### Voltage Controlled Oscillator

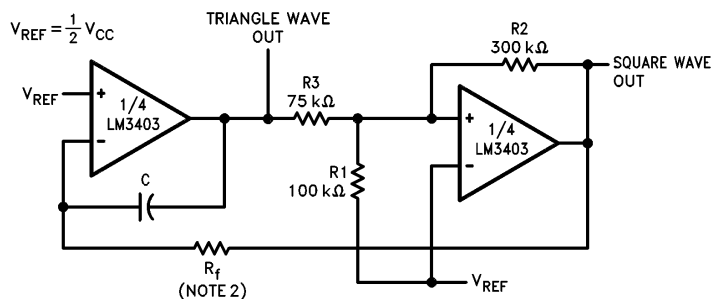


TL/H/10064-12

**Note 1:** Wide Control Voltage Range:  
 $0V \leq V_{CO} \leq 2 (V \pm 1.5V)$

## Typical Applications (Continued)

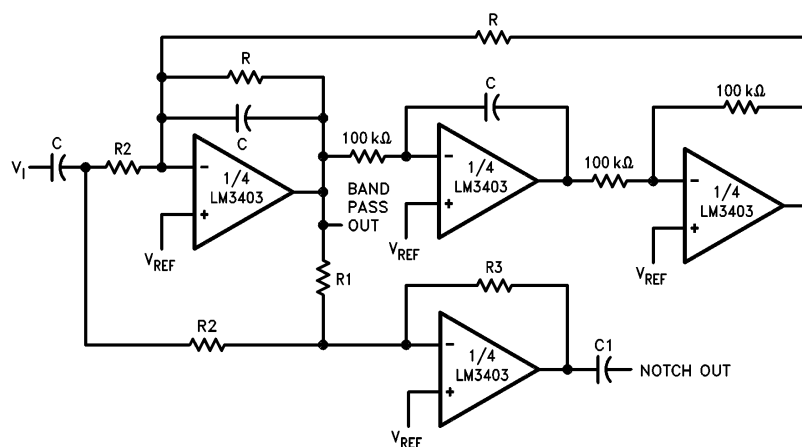
### Function Generator



Note 2:  $f = \frac{R1 + R2}{4CR1R1}$  if  $R3 = \frac{R2R1}{R2 + R1}$

TL/H/10064-13

### Bi-Quad Filter



TL/H/10064-15

$$Q = \frac{BW}{f_o}$$

where:

$T_{BP}$  = Center Frequency Gain

$T_N$  = Bandpass Notch Gain

$$f_o = \frac{1}{2\pi RC} \cdot V_{REF} = \frac{1}{2} V_{CC}$$

$$R1 = QR$$

$$R2 = \frac{R1}{T_{BP}}$$

$$R3 = T_N R2$$

$$C1 = 10 C$$

Example:

$$f_o = 1000 \text{ Hz}$$

$$BW = 100 \text{ Hz}$$

$$T_{BP} = 1$$

$$T_N = 1$$

$$R = 160 \text{ k}\Omega$$

$$R1 = 1.6 \text{ M}\Omega$$

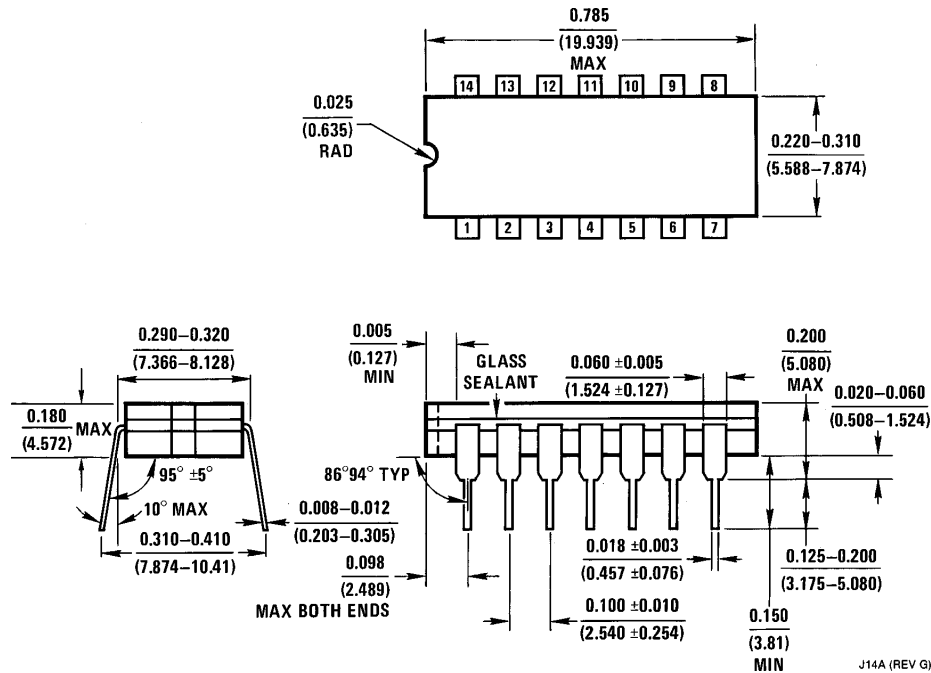
$$R2 = 1.6 \text{ M}\Omega$$

$$R3 = 1.6 \text{ M}\Omega$$

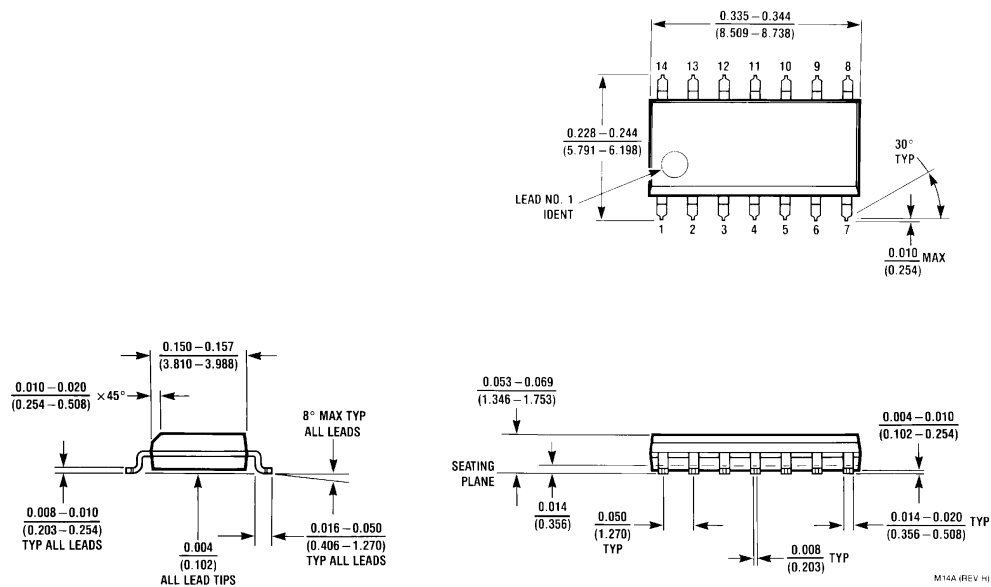
$$C = 0.001 \text{ }\mu\text{F}$$



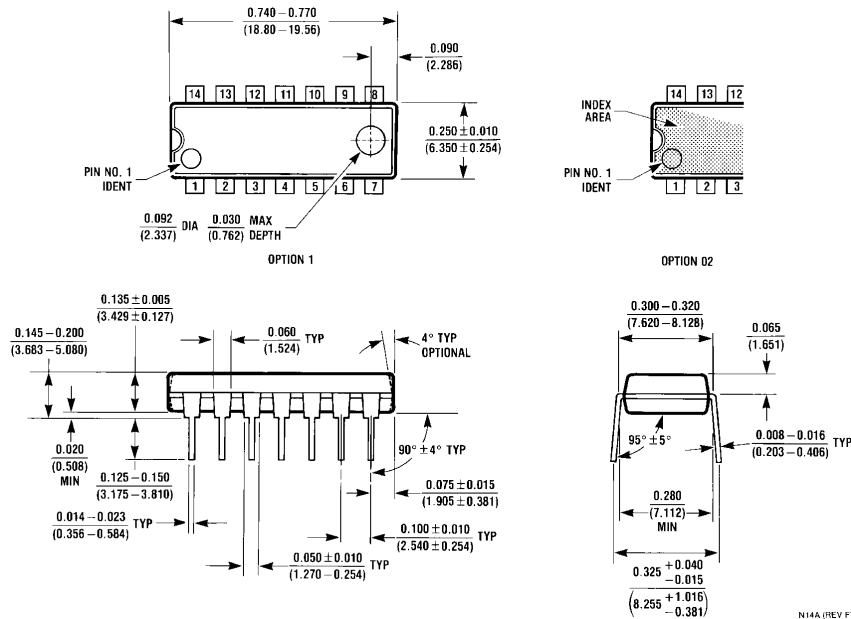
# Physical Dimensions inches (millimeters)



**14-Lead Ceramic Dual-In-Line Package (J)**  
Order Number LM3303J or LM3403J  
NS Package Number J14A



**14-Lead Molded Surface Mount (M)**  
Order Number LM3403M  
NS Package Number M14A

**Physical Dimensions** inches (millimeters) (Continued)

**14-Lead Molded Dual-In-Line Package (N)**  
**Order Number LM3303N or LM3403N**  
**NS Package Number N14A**

N14A (REV F)

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